

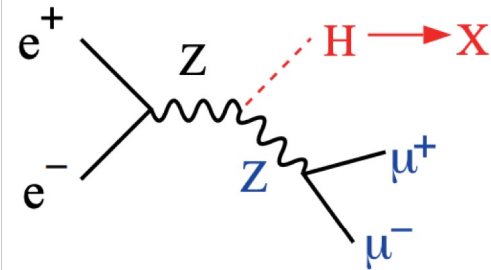
Testbeam measurements with ALICE MAPS prototype

Mirella Vassilev in collaboration with ALICE ITS3 WP3

Future Colliders: Physics Requirements

ZH Process: Primary process at e^+e^- collider at 250 GeV

- Drives requirement on charged track momentum and jet resolution



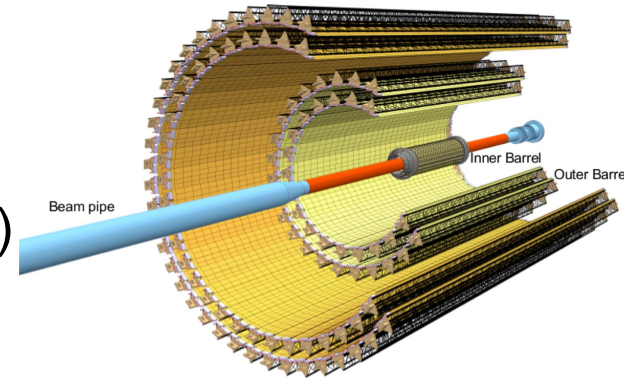
Flavor Tagging: Higgs \rightarrow bb/cc

- Drives requirements on track impact parameter resolution
- Low mass tracker close to beam pipe with $<.3\%$ X_0 per layer (.15% for vertex)
- Thinned to $< 75 \mu\text{m}$, $< 5 \mu\text{m}$ spatial resolution

Physics driven requirements	Running constraints	Sensor specifications
$\sigma_{s.p.}$ 2.8μm		Small pixel $\sim 16 \mu\text{m}$
Material budget 0.15% X_0/layer		Thinning to 50 μm
	Air cooling	low power 50 mW/cm²
r of Inner most layer 16mm	beam-related background	fast readout $\sim 1 \mu\text{s}$
	radiation damage	radiation tolerance
		$\leq 3.4 \text{ Mrad/year}$
		$\leq 6.2 \times 10^{12} n_{eq}/(\text{cm}^2 \text{ year})$

ALICE Inner Tracking System Upgrade Requirements

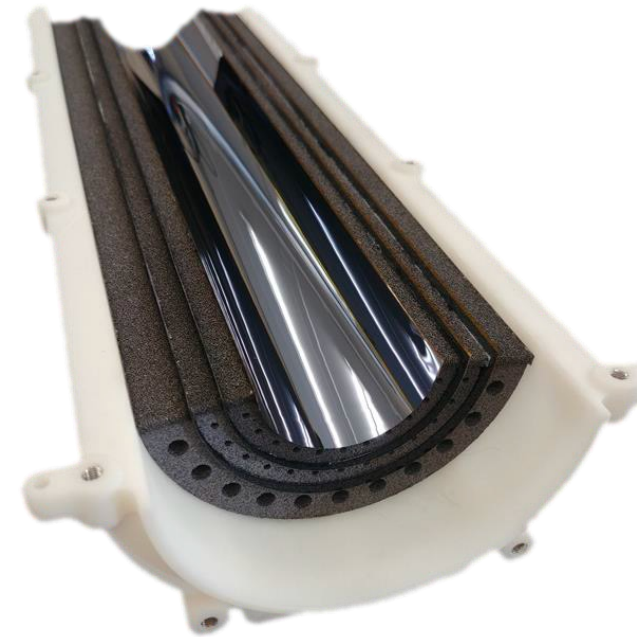
- Replace inner barrel of ITS2 with 3 fully cylindrical bent MAPS layers
- Improved Tracking :
 - Inner tracking layer closer to interaction point
 - Reduced material budget ($0.05\% X_0$ per layer)
 - Spatial resolution (vertex detector: $5\ \mu\text{m}$)
 - Timing resolution $\sim 100\ \text{ns}$
- Readout rates: Pb-Pb event rates of 50 kHz, p-p 200 kHz
- Maximum Radiation load $\sim 10^{13}\ 1\ \text{MeV}\ n_{\text{eq}}/\text{cm}^2$ (NIEL) and 10 kGy (TID)



Detector Layout

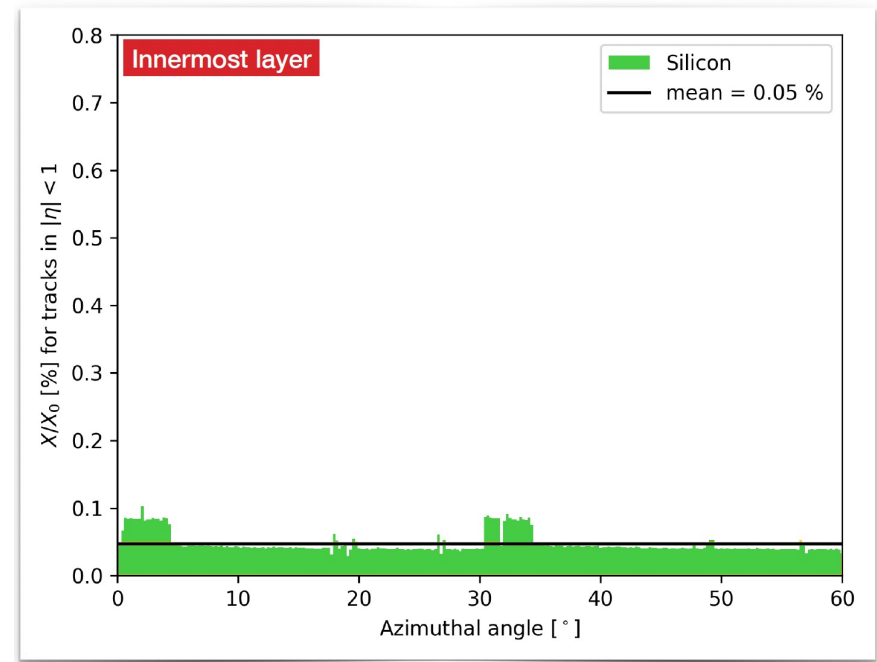
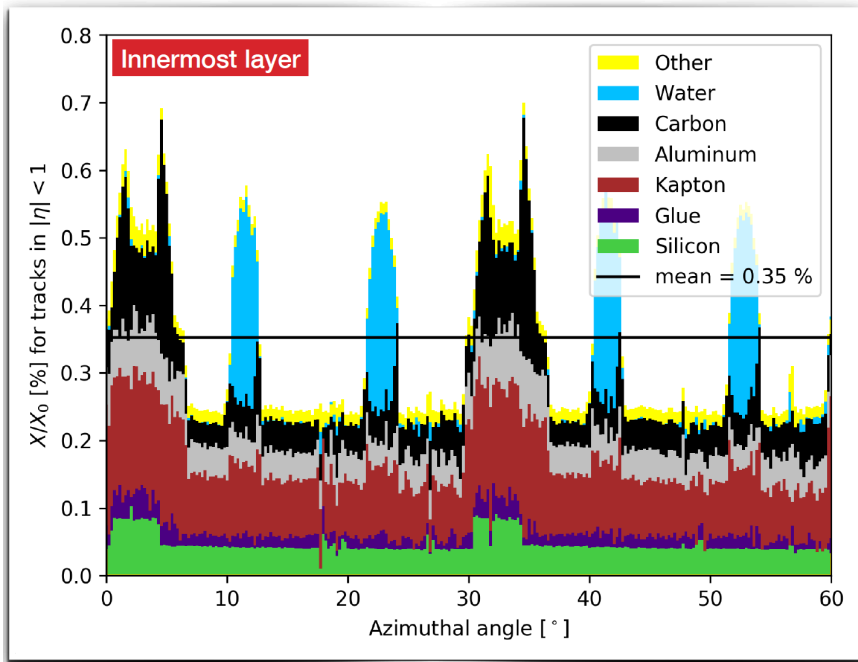
- Inner layer 22 mm(ITS2)-> 18.0 mm(ITS3)
- 3 MAPS layers: two bent half cylinder wafer scale chips
- Carbon foam to hold layers in place

Beampipe inner/outer radius (mm)	16.0/16.5		
IB Layer parameters	Layer 0	Layer 1	Layer 2
Radial position (mm)	18.0	24.0	30.0
Length (sensitive area) (mm)	270	270	270
Pseudo-rapidity coverage ^a	± 2.5	± 2.3	± 2.0
Active area (cm ²)	305	408	508
Pixel sensors dimensions (mm ²)	280 × 56.5	280 × 75.5	280 × 94
Number of pixel sensors / layer	2		
Pixel size (μm ²)	$O(15 \times 15)^b$		



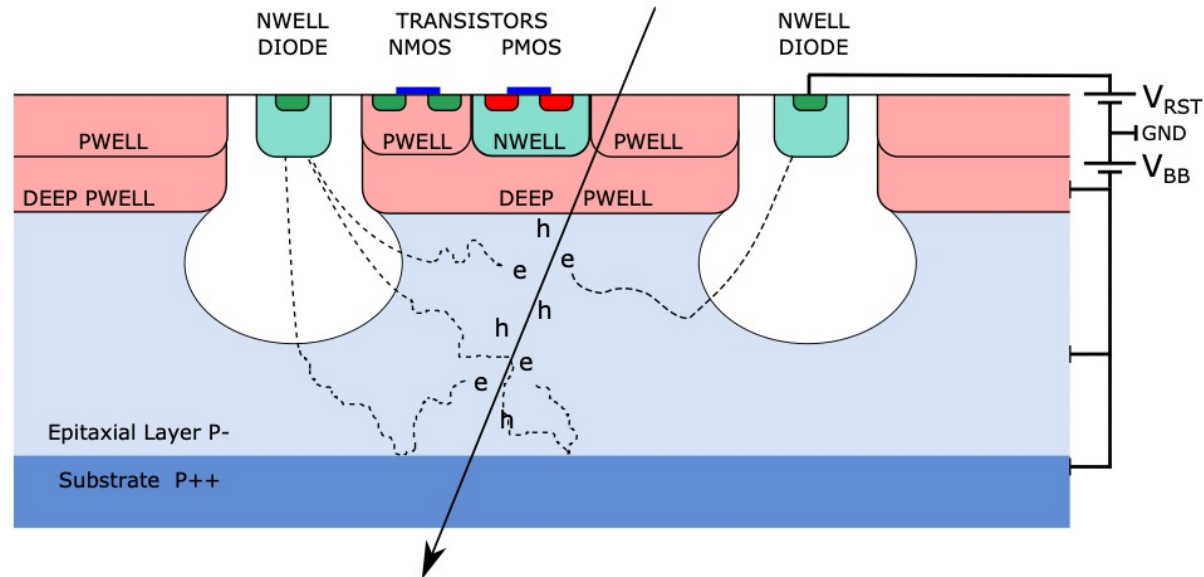
Reduction in Material Budget

- Self supporting cylindrical structure
- Air cooling: low power consumption (below 20 mW/cm²)
- Integrated circuit board



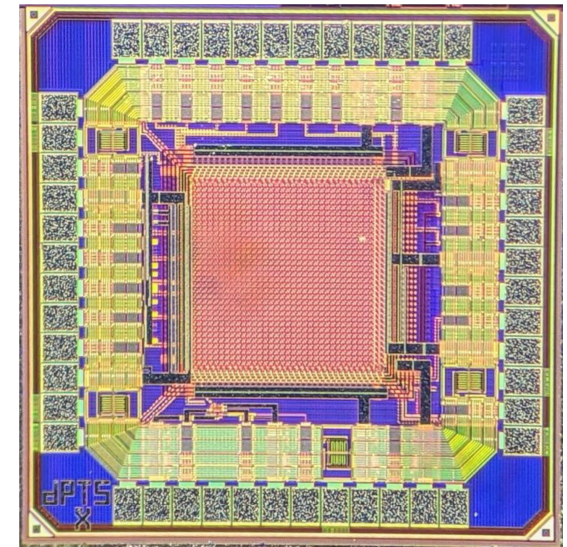
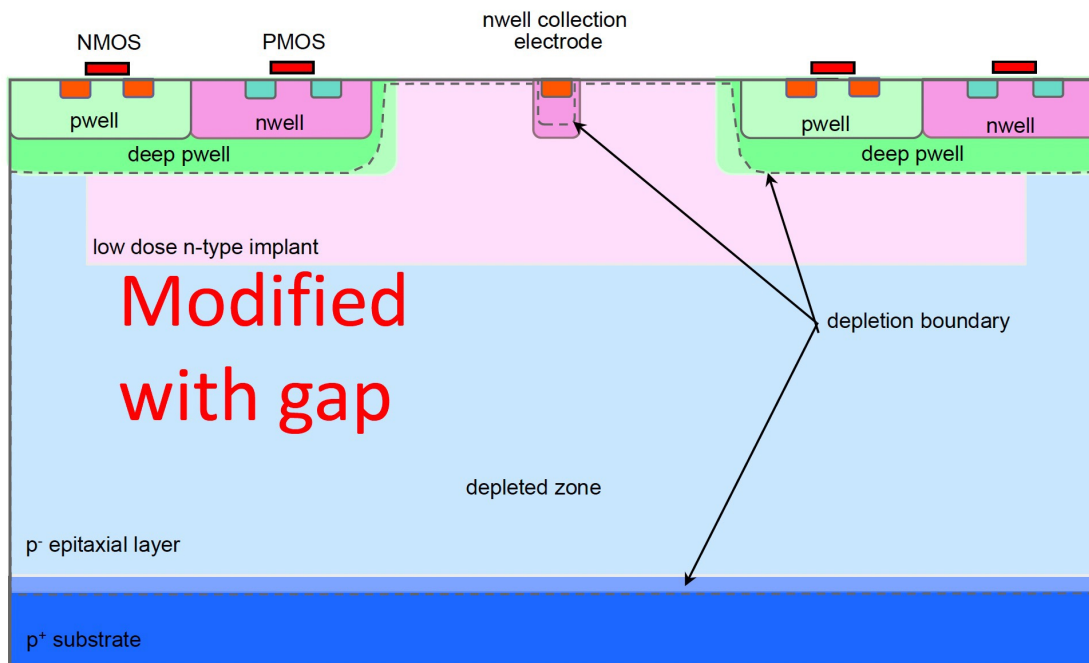
MAPS- Monolithic Active Pixel Sensors

- Combine readout electronics and sensitive volume
- e^-/h^+ pairs created by traversing particles, diffuse/drift to electrodes
- Small pixel size, large S/N, low power consumption, low material budget, low cost
- **Compared to hybrid: lower radiation resistance, smaller signal,**
not constrained by size of bump bonds



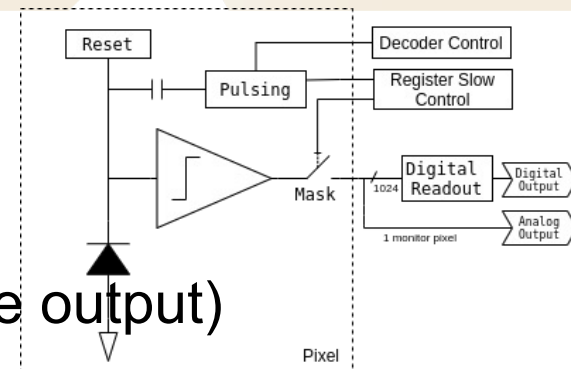
DPTS: Digital Pixel Test Structure Sensor Design

- Back bias + low dose n-type implant: enlarge depletion region at collection diode
- Fully depleted sensors: faster charge collection, improved timing



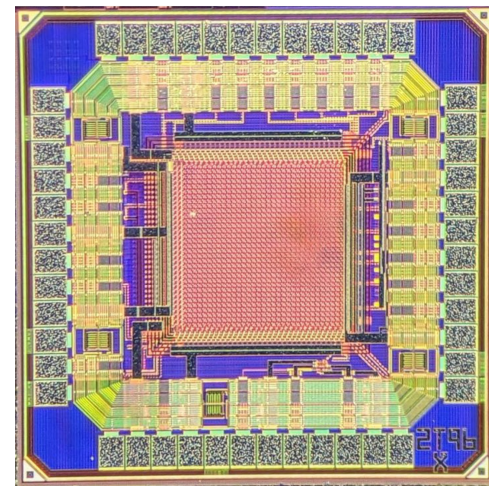
DPTS: Digital Pixel Test Structure

- 32 x 32 pixels, 15 μm pitch
 - 1.5 mm x 1.5 mm
 - In pixel amplification and discrimination
 - Asynchronous digital readout with ToT (single output)
 - Pixel pulsing, monitor pixel (analog)
-
- Goals: Proof of concept and characterization of charge collection



Radiation hardness targets:

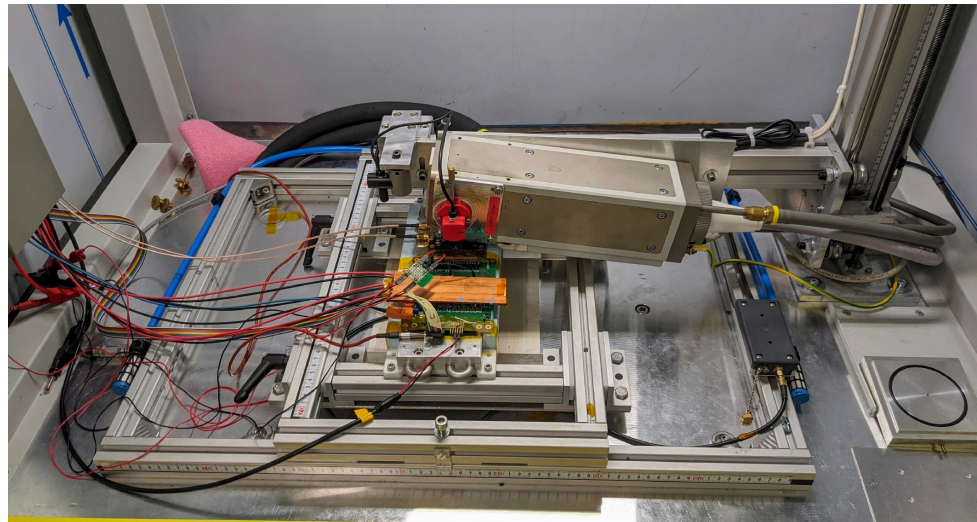
- TID (total ionizing dose) 1 Mrad
- NIEL (nonionizing energy loss) 10^{13} n/cm²



DPTS Irradiation

- TID – up to 10 Mrad
- NIEL- up to 10^{15} 1 MeV n_{eq}/cm^2
- NIEL Irradiation @ JSI Ljubljana with neutrons
- TID irradiation @ CERN X-ray Machine
 - Different irradiation rates 12-100 krad/min
 - Continuously and in intervals

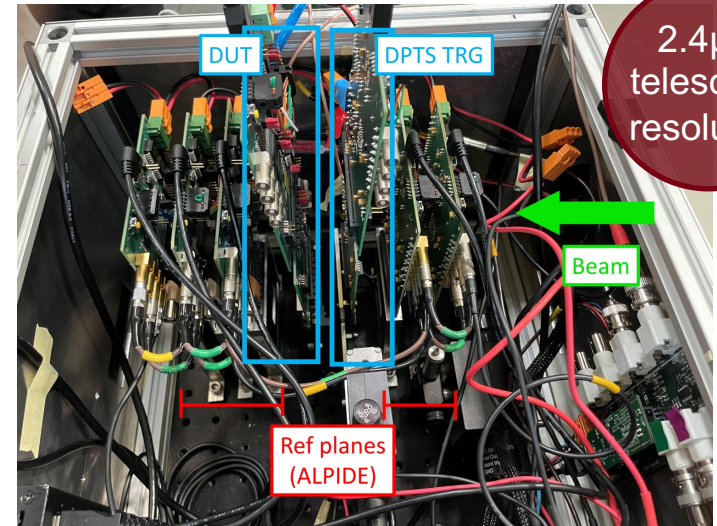
Chip serial	NIEL irradiation level
DPTSOW22B7	non irradiated
DPTSOW22B3	Irradiated TID 1 MRad
DPTSXW22B10	Irradiated NIEL 1E13
DPTSXW22B12	Irradiated NIEL 1E14
DPTSOW22B17	Irradiated NIEL 1E15
DPTSXW22B26	Irradiated TID 1 Mrad
DPTSXW22B8	Irradiated TID 10 Mrad



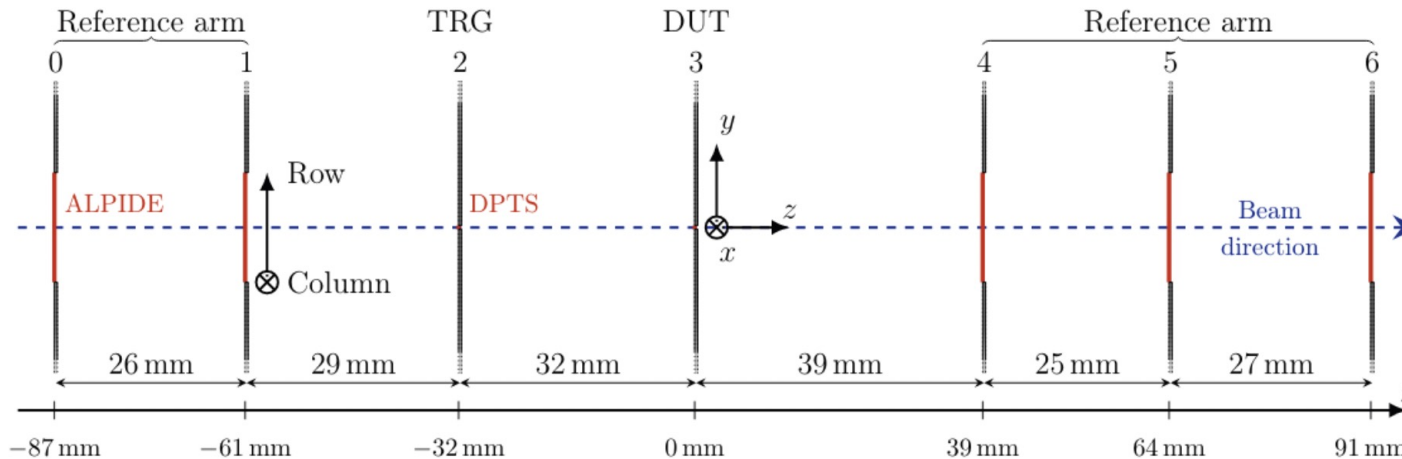
Testbeam Setup

CERN PS 29th June-13th July 2022

- DPTS as trigger
- 5 ALPIDE reference planes
- DUT maintained at 20°C
- 10 GeV positive hadron beam
- EUDAQ and Corryvreckan: DAQ and analysis framework



2.4 μ m telescope resolution

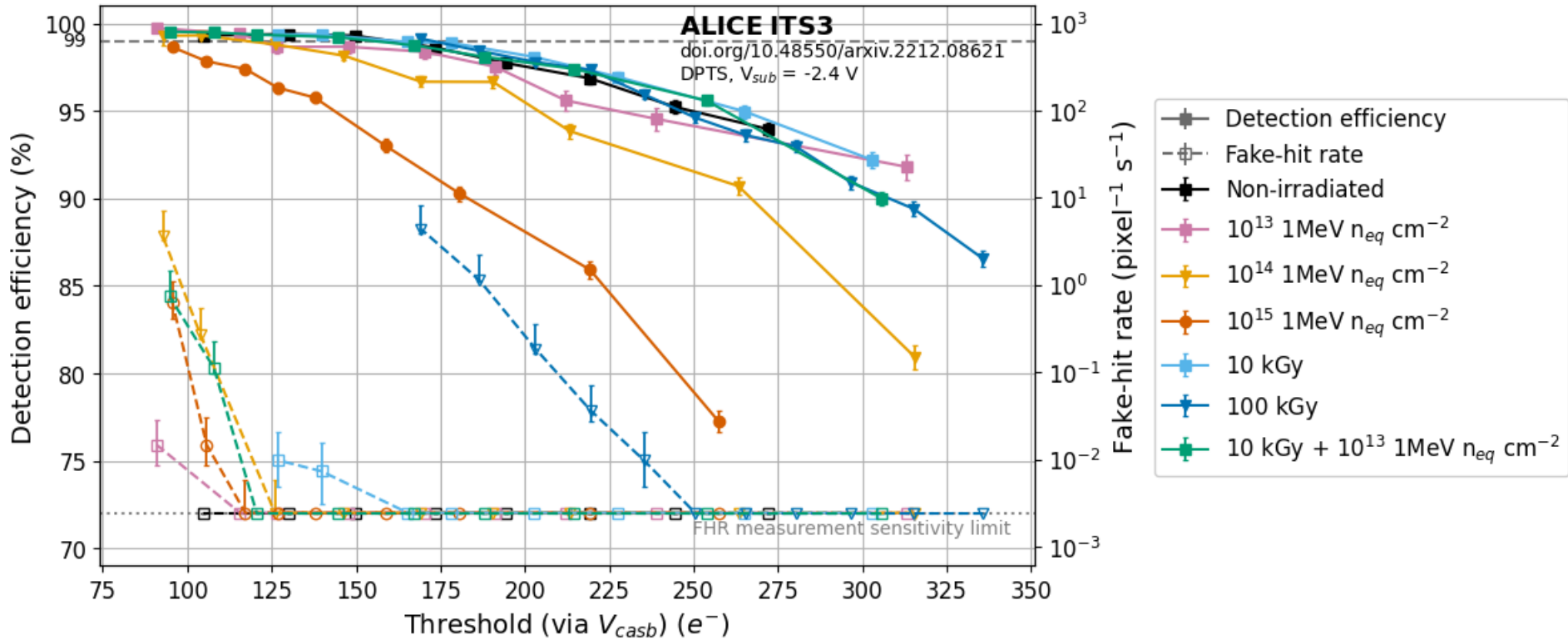


Chip serial	NIEL irradiation level
DPTSOW22B7	non irradiated
DPTSOW22B3	Irradiated TID 1 Mrad
DPTSXW22B10	Irradiated NIEL 1E13
DPTSXW22B12	Irradiated NIEL 1E14
DPTSOW22B17	Irradiated NIEL 1E15
DPTSXW22B26	Irradiated TID 1 Mrad
DPTSXW22B8	Irradiated TID 10 Mrad

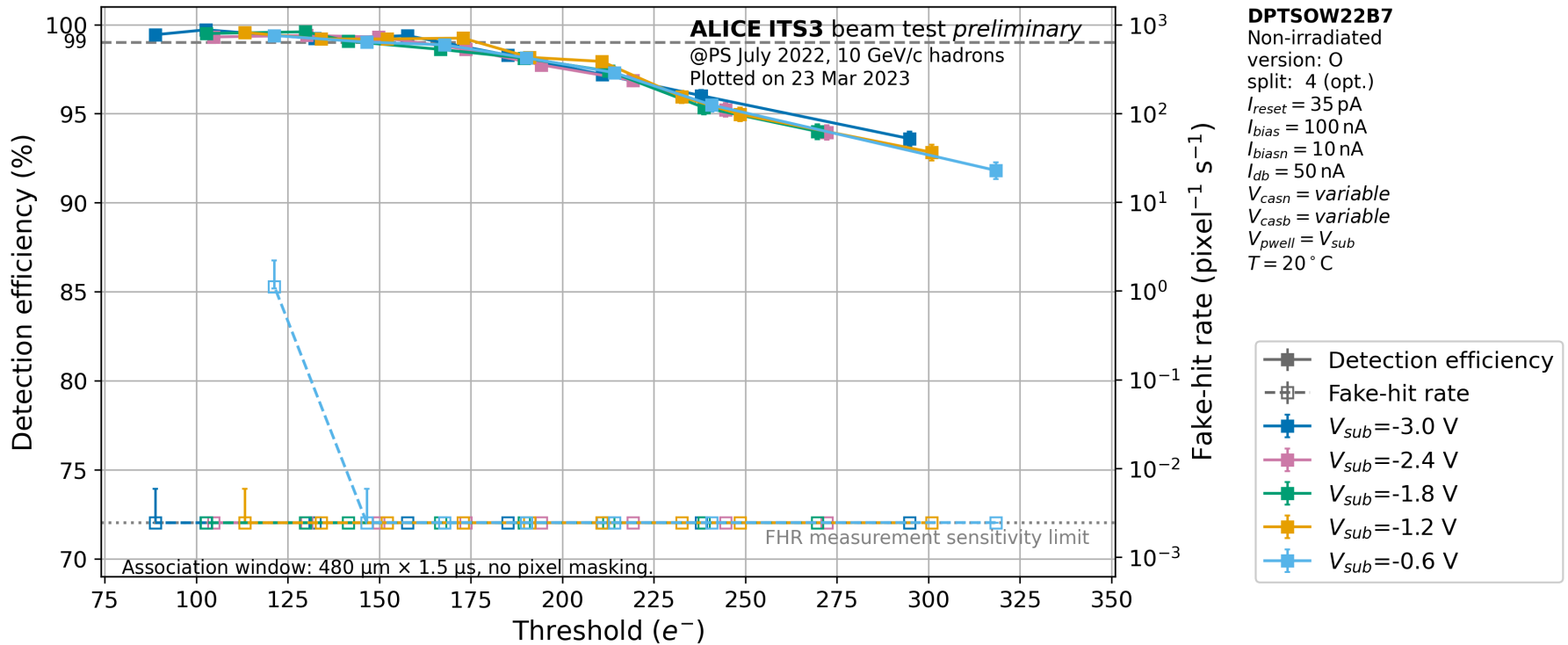
Testbeam Analyses

- Total efficiency
- In-Pixel Analyses: Efficiency, Mean Cluster Size
- Spatial Resolution
- Timing Resolution

Total Efficiency



Total Efficiency: Nonirradiated

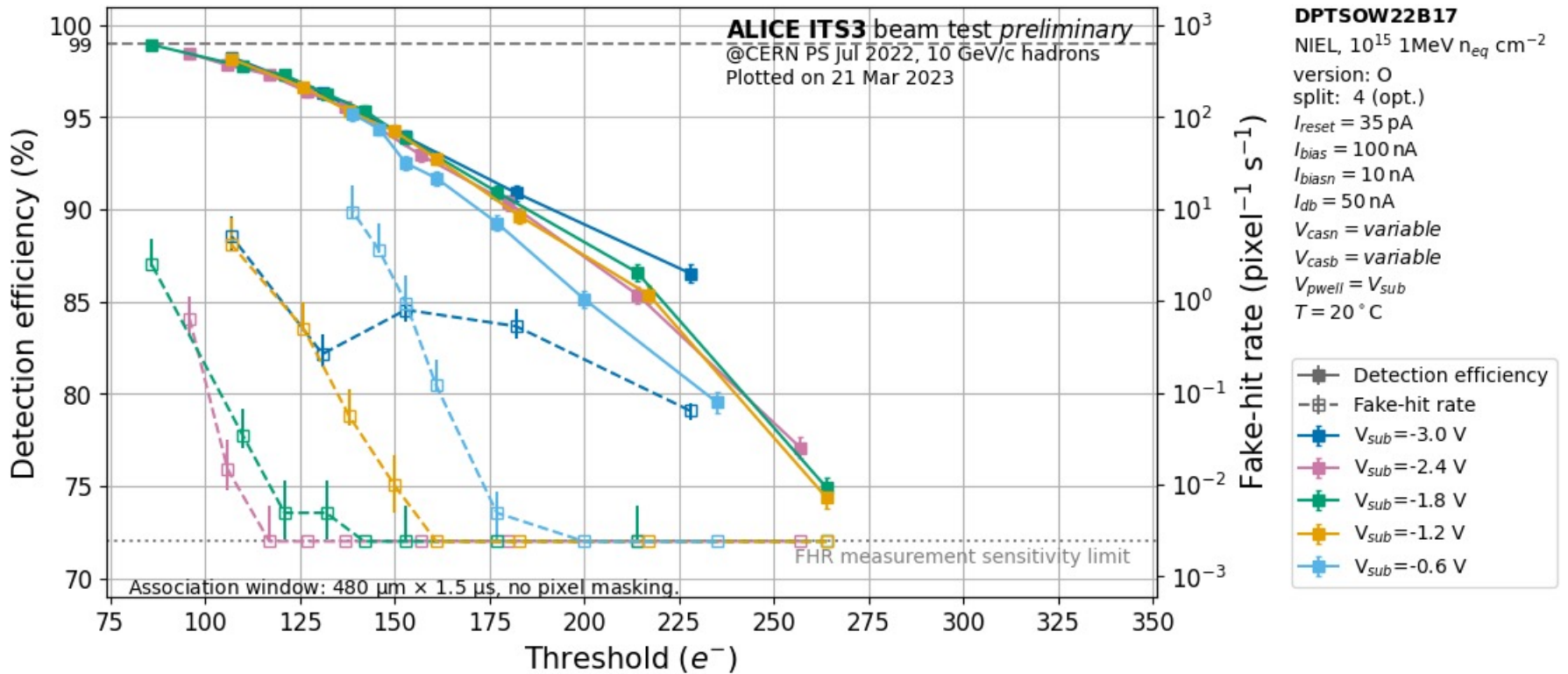


high statistic runs:

Efficiency: .911
 Mean Threshold: 315

Efficiency: .951
 Mean Threshold: 265

Total Efficiency: NIEL Irradiated 10^{15} 1 MeV n_{eq} cm^{-2}



Efficiency: 0.928
 Mean Threshold: 160

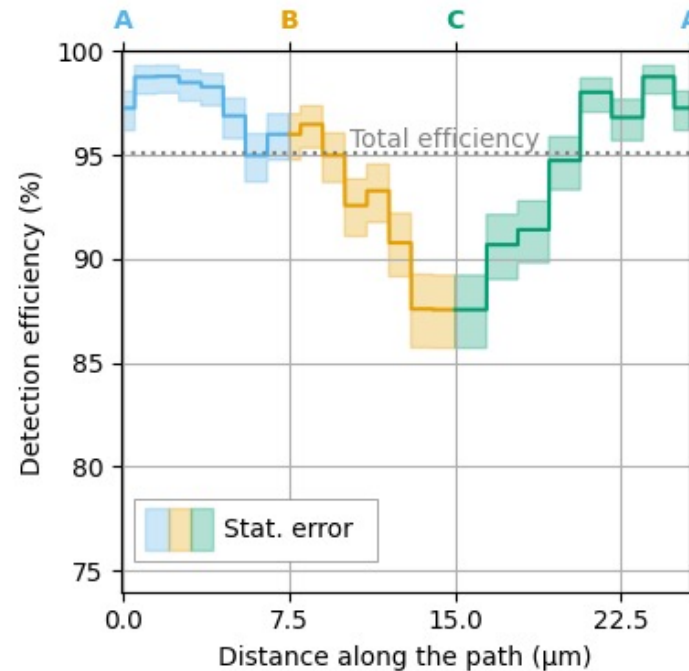
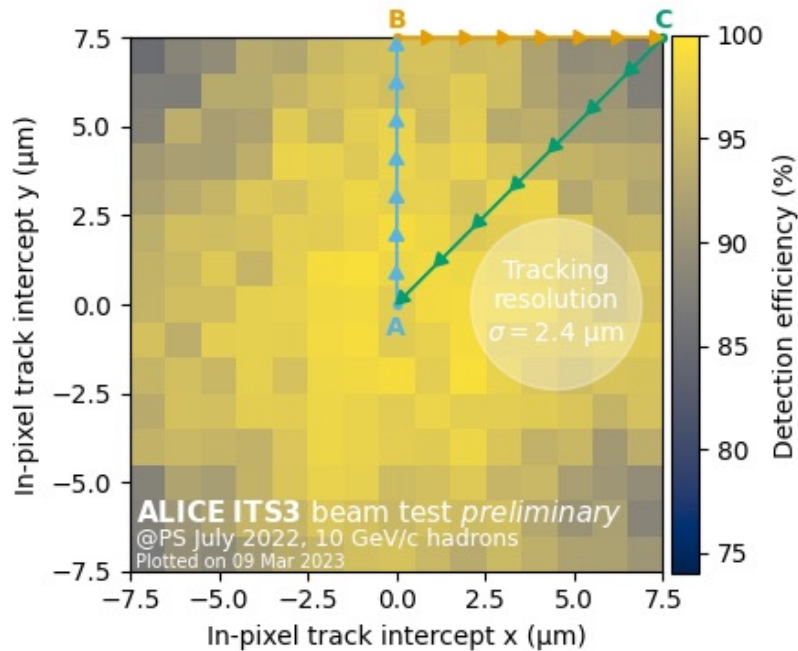
Efficiency: 0.956
 Mean Threshold: 135

Efficiency: 0.954
 Mean Threshold: 145

Efficiency: 0.963
 Mean Threshold: 130

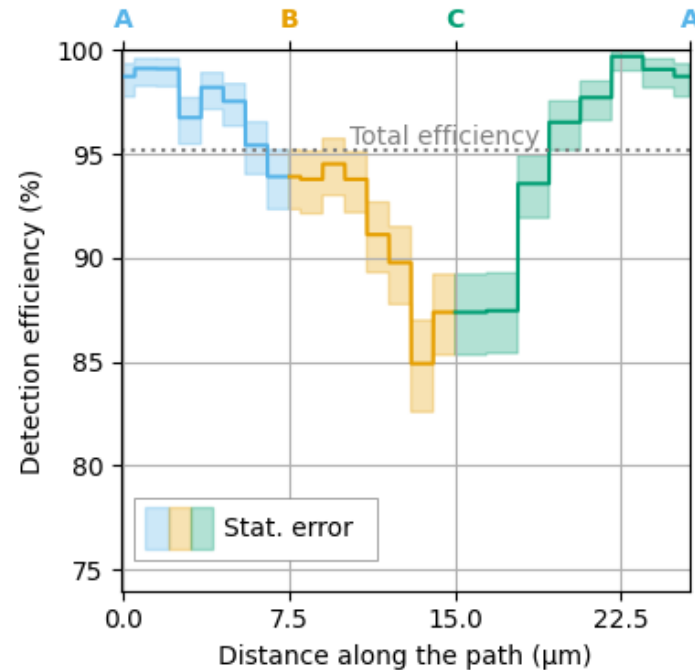
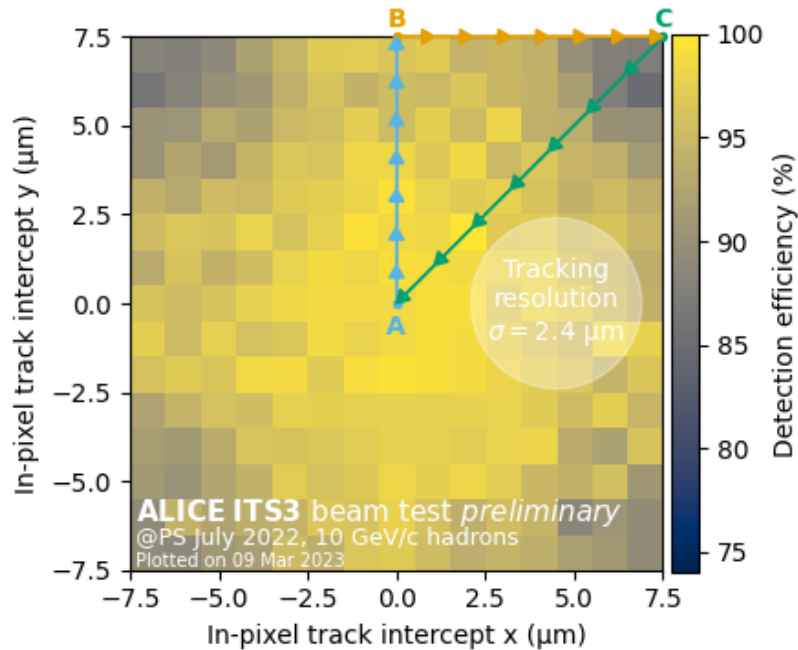
high statistic runs:

In Pixel Efficiency: Nonirradiated



DPTSOW22B7
 Non-irradiated wafer: 22
 chip: 7
 version: 0
 split: 4
 $I_{reset} = 35 \text{ pA}$
 $I_{bias} = 100 \text{ nA}$
 $I_{biasn} = 10 \text{ nA}$
 $I_{db} = 50 \text{ nA}$
 $V_{casn} = 400 \text{ mV}$
 $V_{casb} = 325 \text{ mV}$
 $V_{pwell} = V_{sub} = -3.0 \text{ V}$
 Threshold = $265 e^-$

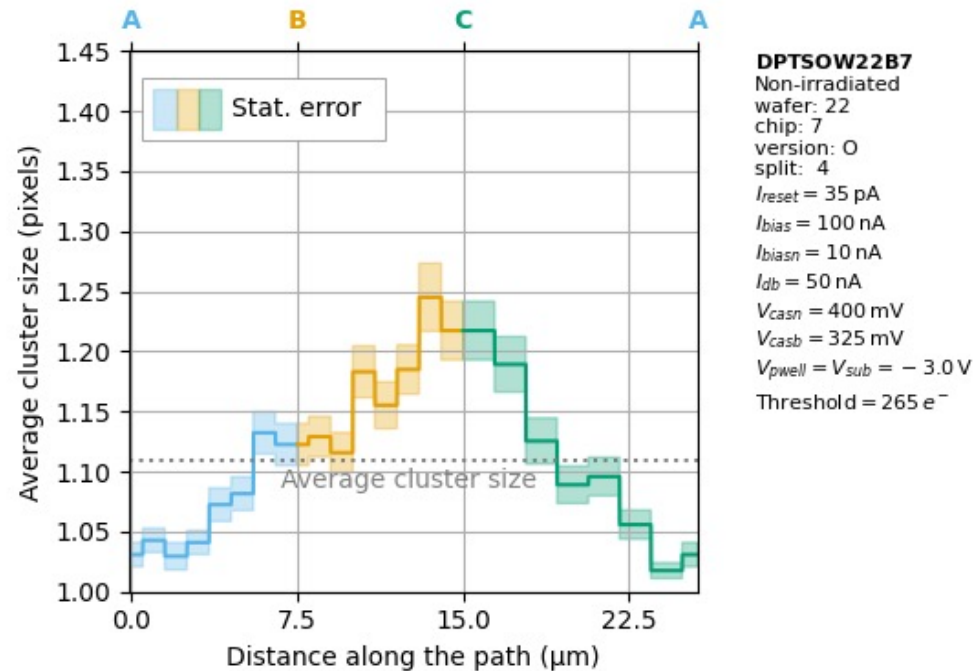
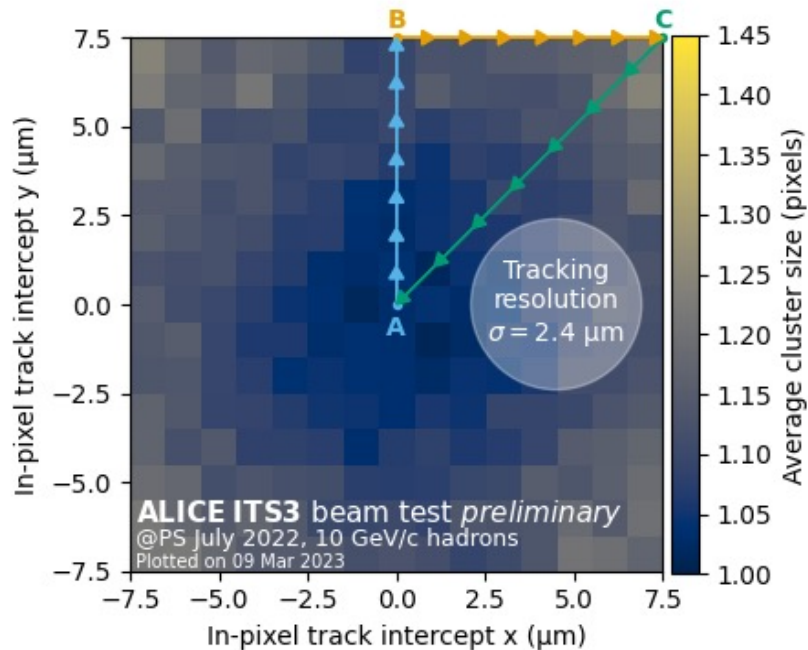
In Pixel Efficiency: NIEL Irradiated 10^{15} 1 MeV n_{eq} cm^{-2}



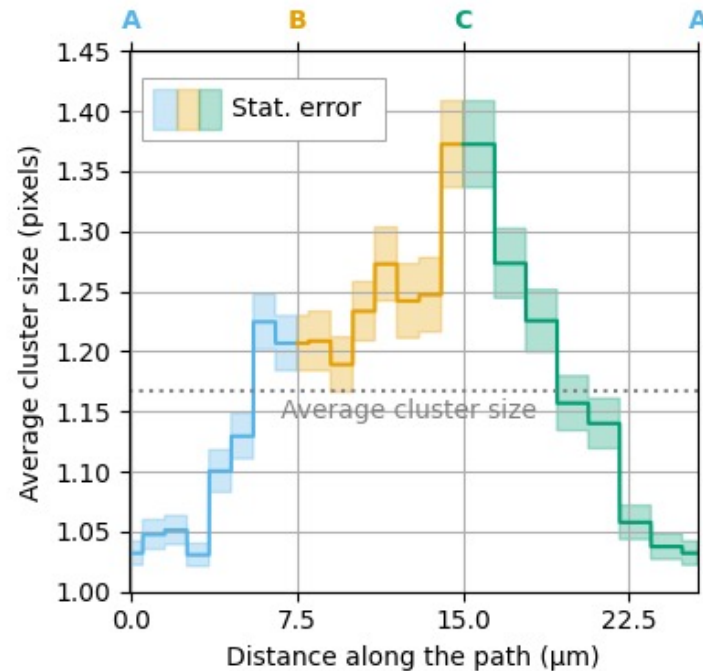
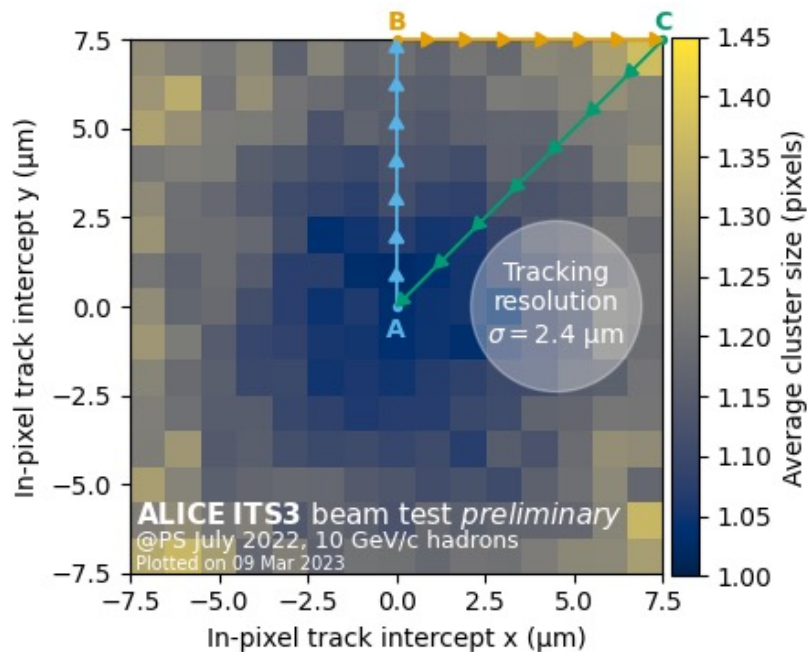
DPTSOW22B17
 10^{15} 1MeV n_{eq} cm^{-2}
 wafer: 22
 chip: 7
 version: 0
 split: 4
 $I_{reset} = 35$ pA
 $I_{bias} = 100$ nA
 $I_{biasn} = 10$ nA
 $I_{db} = 50$ nA
 $V_{casn} = 280$ mV
 $V_{casb} = 280$ mV
 $V_{pwell} = V_{sub} = -1.8$ V
 Threshold = $145 e^-$

Mean Cluster Size: Nonirradiated

- Cluster is a set of adjacent pixels that go over threshold



Mean Cluster Size : NIEL Irradiated 10^{15} 1 MeV n_{eq} cm^{-2}

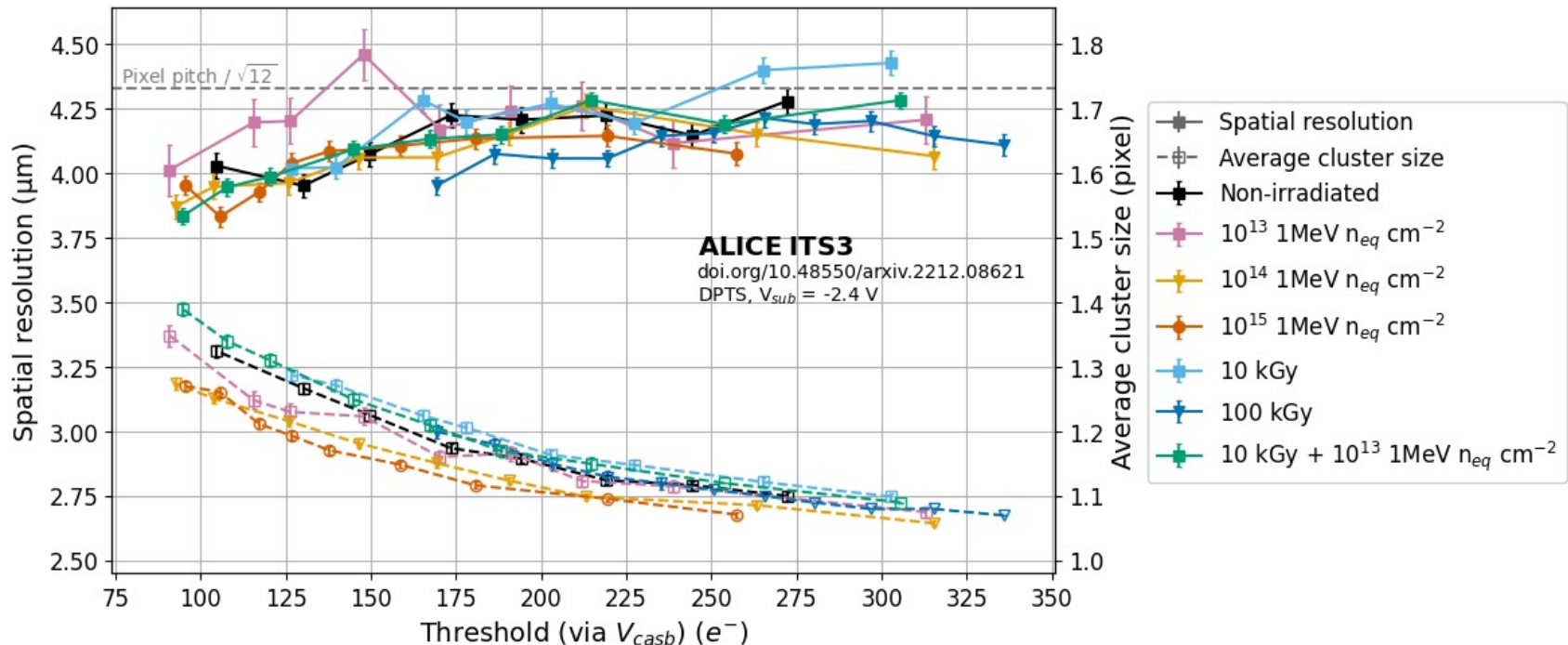


DPTSOW22B17
 10^{15} 1MeV n_{eq} cm^{-2}
 wafer: 22
 chip: 7
 version: 0
 split: 4
 $I_{reset} = 35$ pA
 $I_{bias} = 100$ nA
 $I_{biasn} = 10$ nA
 $I_{db} = 50$ nA
 $V_{casn} = 280$ mV
 $V_{casb} = 280$ mV
 $V_{pwell} = V_{sub} = -1.8$ V
 Threshold = $145 e^-$

Spatial Resolution:

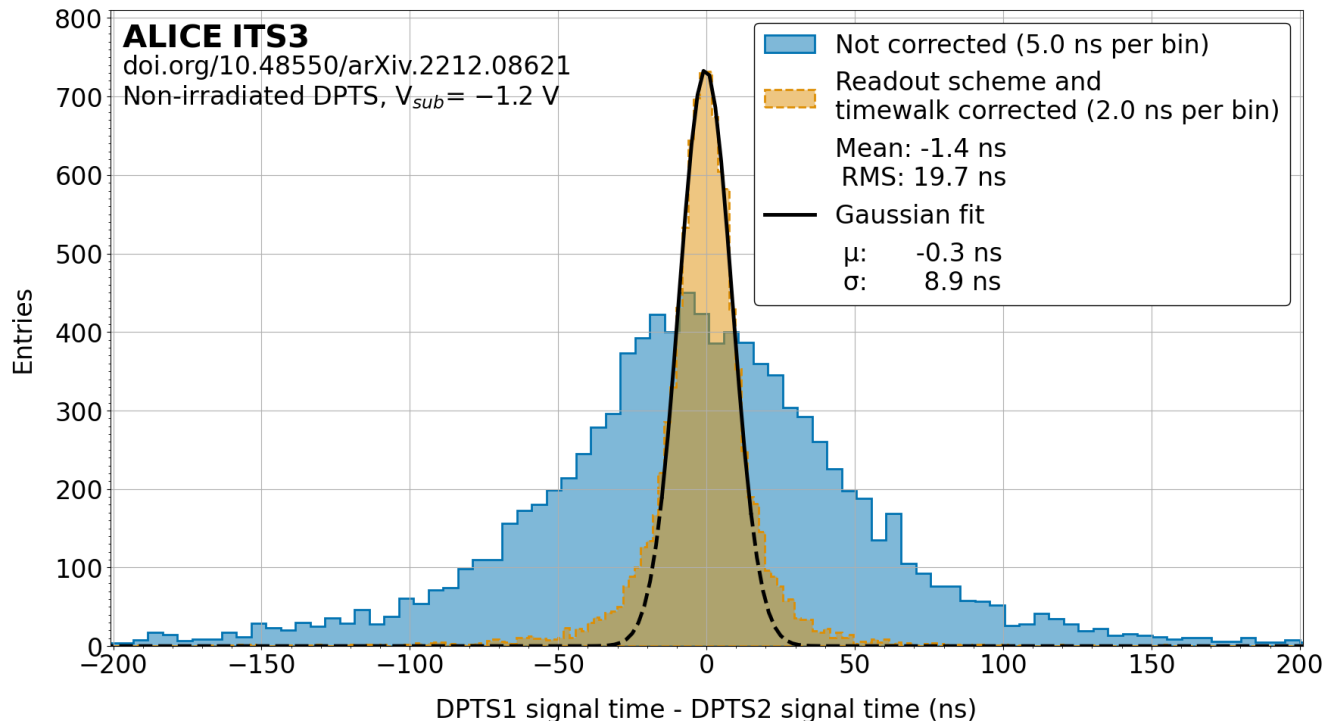
- Requirement: 5 μm
- Telescope resolution: 2.4 μm
- Spatial resolution is average of row/column resolutions
- Fit gaussian to spatial residual distributions:

$$\sigma^2 = \sigma_{\text{row/column}}^2 - \sigma_{\text{telescope}}^2$$



Timing Resolution:

- Requirement: 100ns
- 5.4 GeV electron beam
- Distribution of time residuals: $\sigma_t = 6.3 \pm 0.1$ ns
- Readout scheme correction: time delay between even and odd columns



Performance Summary

- ITS3 Radiation hardness targets:
 - TID (total ionizing dose) 1 Mrad
 - NIEL (nonionizing energy loss) 10^{13} 1 MeV n/cm²
- Spatial resolution (vertex detector: 5 μ m) : <4.33 μ m
- Timing resolution \sim 100 ns : 6.3 ns
- Working points with 99% detection efficiency at room temperature even up to 10^{15} 1 MeV n/cm²
- More R&D needed to realize stitched sensors

- MAPs are established vertex detectors that have widespread applications, including at future colliders!

e⁺e⁻ Requirements vs. ALICE

- MAPS are viable technology in future e⁺e⁻ colliders
- Similar requirements to ALICE ITS3 Upgrade

ALICE
 5 μm
 0.05 % X₀/layer
 18 mm

Physics driven requirements	Running constraints	Sensor specifications
$\sigma_{s.p.}$ 2.8μm		Small pixel ~16 μm
Material budget 0.15% X ₀ /layer		Thinning to 50 μm
	Air cooling	low power 50 mW/cm ²
r of Inner most layer 16mm	beam-related background	fast readout ~1 μs
	radiation damage	radiation tolerance ≤3.4 Mrad/year ≤6.2×10 ¹² n _{eq} / (cm ² year)

ALICE
 15 μm
 <50 μm
 20 mW / cm²
 -
 1 Mrad
 10¹³ 1 MeV n_{eq}/cm²

- More R&D on fast readout/stitching/power consumption